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WIDE-BAND LOW-NOISE DISTRIBUTED FRONT-END FOR MULTI-GIGABIT CPFSK RECEIVERS

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Abstract — In this paper a distributed optical front-end amplifier for a coherent optical CPFSK receiver is presented. The measured average input noise current density is 20 pA/√Hz in a 3–13 GHz bandwidth. This is the lowest value reported for a distributed optical front-end in this frequency range. The front-end is tested in a system set-up at a bit rate of 2.5 Gbit/s and a receiver sensitivity of -41.5 dBm is achieved at a 10^-9 bit error rate.

INTRODUCTION

Coherent optical heterodyne receivers have been demonstrated both in laboratories [1] and field trials [2]. Due to the relatively high complexity of the coherent receiver a monolithic realisation would be required for operational applications. A receiver for the commonly used modulation scheme, CPFSK (Continuous Phase Frequency Shift Keying), is shown in fig. 1. The receiver normally operates at an IF (Intermediate Frequency) 2-4 times the bit rate with a bandwidth approximately twice the bit rate. In order to obtain a high receiver sensitivity using a moderate local oscillator power a wide-band low-noise front-end in the receiver is required.

Different tuned circuit topologies have been suggested [3,4], but these topologies are difficult to implement as monolithic circuits due to their poor stability properties. Another circuit topology, which has not been investigated very much, is the distributed optical front-end amplifier [5,6] as shown in fig. 2. In this front-end the junction capacitance of the photodiode and the bond wire between the photodiode and the MMIC (l_g1) are incorporated in an artificial gate transmission line [6]. On-chip the artificial gate transmission line consists of the gate-source capacitances of the FETs and the inductances l_g2–l_g5.

CIRCUIT DESIGN

The distributed optical front-end is based on a GaInAs/InP p-i-n photodiode chip from BT&D and a full-custom designed MMIC including a

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**Fig. 1** CPFSK system set-up with Mach-Zehnder Interferometer (MZI).

**Fig. 2** Simplified schematic of distributed optical front-end amplifier.

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distributed amplifier. The MMIC was realised using a GaAs ion-implanted MESFET process with an fT of 20 GHz from GEC-Marconi. The front-end employs a single photodiode to decrease the parasitic junction capacitance. However, the use of a single photodiode does not remove the laser RIN (Relative Intensity Noise), in contrast to a balanced front-end [3,5], and may reduce the receiver sensitivity. Therefore, a recently proposed fibre Mach-Zehnder interferometer is used to suppress the local oscillator RIN [7]. By using this all optical RIN suppressing interferometer the signal and local oscillator powers are efficiently exploited using a single photodiode front-end. The layout of the designed MMIC is shown in fig. 3 and measures 1.8 mm by 1.8 mm. The inductances lG2-lG5 were realised as short pieces of microstrip line. The inductances in the artificial drain transmission line, lD1-lD4, were realised as a combination of spiral inductors and microstrip line. MIM (Metal Insulator Metal) capacitors were used as dc-blocks on-chip, resulting in a low frequency cut-off at 2 GHz. The photodiode and the MMIC were bonded on alumina thinfilm substrate into a complete optical front-end.

FRONT-END CHARACTERISATION

The transimpedance and the equivalent input noise current density were measured using a lightwave test-set HP83420A and a spectrum analyser. The results of the transimpedance and equivalent input noise current density measurements are shown in fig. 4 together with the simulations. A very good agreement is observed between the measured and simulated transimpedance except for the dip at 9 GHz, which was caused by a defective thinfilm resistor in the photodiode bias circuitry.

The average input noise current density is 20 pA/√Hz within a bandwidth of 3–13 GHz, this value is close to previously published results for tuned optical front-ends in the same frequency range [3]. The transimpedance in the same frequency range is in average 38 dBΩ.

![Fig. 4 Measured and simulated transimpedance and equivalent input noise current density of distributed front-end. Solid lines are measurements and dashed lines are simulations.](image)

The different noise contributions in the front-end were simulated to clarify their influence on the total front-end input noise. The total noise was divided into the following sources:

- MESFET noise, $\langle \dot{q}_{\text{FET}} \rangle$.
- Thermal noise from the photodiode including losses in interconnect network between photodiode and the MMIC, $\langle \dot{q}_{\text{diode}} \rangle$.
• Thermal noise due to losses in the drain transmission line, \( \langle i_{\text{drain}}^2 \rangle \).
• Thermal noise due to losses in the gate line, \( \langle i_{\text{gate}}^2 \rangle \).
• Noise from the terminations (\( Z_g \) and \( Z_d \) in fig. 2), \( \langle i_{\text{term}}^2 \rangle \).

These five contributions are uncorrelated and the total squared input noise current density can be expressed as

\[
\frac{d\langle i_{\text{eq}}^2 \rangle}{df} = \frac{d\langle i_{\text{FET}}^2 \rangle}{df} + \frac{d\langle i_{\text{diode}}^2 \rangle}{df} + \frac{d\langle i_{\text{drain}}^2 \rangle}{df} + \frac{d\langle i_{\text{gate}}^2 \rangle}{df} + \frac{d\langle i_{\text{term}}^2 \rangle}{df}
\]  

(1)

Fig. 5 shows the contribution from the five different noise sources in percent of the total noise as a function of frequency. As observed from this figure the noise from the FETs is dominating over the entire passband followed by the diode noise. The three remaining noise sources are almost insignificant except for the noise from the terminations which exhibit a peak around 6 GHz. Each of the terms has been integrated over the frequency range from 3-13 GHz and listed in table I. From this table we conclude that the dominating noise contribution comes from the FETs, whereas noise from transmission line losses and terminations is negligible. This is in contrast to previous publications where the terminations (\( Z_g \) and \( Z_d \) in fig. 2) have been considered as important noise source in the distributed front-end amplifier, especially at low frequencies [5]. Since a general purpose MESFET foundry process with moderate noise performance was used to realize the MMIC, the FET noise contribution is high. It is therefore possible to decrease the equivalent input noise current in fig. 4 considerably by using FETs with lower noise.

### Table I

<table>
<thead>
<tr>
<th>Noise source</th>
<th>Contribution</th>
</tr>
</thead>
<tbody>
<tr>
<td>MESFETs</td>
<td>68%</td>
</tr>
<tr>
<td>Photodiode</td>
<td>22%</td>
</tr>
<tr>
<td>Drain line</td>
<td>1%</td>
</tr>
<tr>
<td>Gate line</td>
<td>4%</td>
</tr>
<tr>
<td>Terminations</td>
<td>5%</td>
</tr>
</tbody>
</table>

Integrated over 3-13 GHz.

**SYSTEM EXPERIMENTS**

The distributed optical front-end was tested in a 2.5 Gbit/s system set-up as shown in fig. 1. Two \( \lambda/4 \) shifted MQW DFB lasers with a 1.5 MHz linewidth were used as transmitter and local oscillator laser [8]. The CPFSK signal was obtained by directly modulating the transmitter laser with a pattern generator. In addition to the distributed optical front-end commercial microwave amplifiers were used as IF amplifiers and a 7.7–12.9 GHz microstrip filter was used as noise filter. The IF was 10 GHz and a modulation index of 0.8 was used. Two experiments with and without the all-optical Mach–Zehnder RIN suppressor were performed. Fig. 6 shows the measured bit error rate curves for the two experiments. The improvement of 1.5 dB in receiver sensitivity is in close agreement with expectations when the LO RIN and the LO power are considered [7].

**CONCLUSION**

A low-noise optical front-end with a 10 GHz bandwidth has been presented. The front-end
Fig. 6 Measured bit error rate curves at 2.5 Gbit/s with and without RIN suppression using a $2^7$-1 PRBS.

exhibited an average equivalent input noise current density of 20 pA/√Hz in a 3-13 GHz bandwidth and an average transimpedance of 38 dBΩ. The noise of the front-end is lower than previously published results for distributed optical front-ends, in spite of the moderate noise performance of the employed MESFETs. The dominating noise source was found to be the FET noise indicating that the noise of the front-end can be further decreased if lower noise FET processes are used, such as HEMT processes. The presented front-end was also tested in a CPFSK system set-up, with an intermediate frequency of 10 GHz. A sensitivity as low as -41.5 dBm at a bit rate of 2.5 Gbit/s was obtained. To our knowledge this is the best receiver sensitivity obtained with a distributed optical front-end amplifier in a coherent heterodyne receiver at 2.5 Gbit/s.

ACKNOWLEDGEMENTS

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